PDTD113E series

NPN 500 mA, 50 V resistor-equipped transistors;R1 = 1 kΩ, R2 = 1 kΩRev. 02 — 16 November 2009Pro

Product data sheet

1. Product profile

1.1 General description

500 mA NPN Resistor-Equipped Transistors (RET) family.

Table 1. Product overview

Type number	Package		PNP complement	
	NXP	JEITA	JEDEC	
PDTD113EK	SOT346	SC-59A	TO-236	PDTB113EK
PDTD113ES ^[1]	SOT54	SC-43A	TO-92	PDTB113ES
PDTD113ET	SOT23	-	TO-236AB	PDTB113ET

[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 500 mA output current capability

1.3 Applications

- Digital application in automotive and industrial segments
- Controlling IC inputs

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
lo	output current (DC)		-	-	500	mA
R1	bias resistor 1 (input)		0.7	1	1.3	kΩ
R2/R1	bias resistor ratio		0.9	1.0	1.1	



- Reduces component count
- Reduces pick and place costs
- ±10 % resistor ratio tolerance
- Cost saving alternative for BC817 series in digital applications
- Switching loads

2. Pinning information

Pin	Description	Simplified outline	Symbol
SOT54			
1	input (base)		
2	output (collector)		
3	GND (emitter)	001aab347	1 R1 R2 006aaa145
SOT54A			
1	input (base)		
2	output (collector)		
3	GND (emitter)	1 2 001aab348	1 R1 R2 006aaa145
SOT54 va	riant		
1	input (base)		
2	output (collector)		
3	GND (emitter)	Cm Cm D O01aab447	1 R2 006aaa145
SOT23, S	OT346		
1	input (base)		
2	GND (emitter)	3	
3	output (collector)	12	1 R2 sym007

3. Ordering information

Table 4. Orde	ring inform	ation				
Type number	Package	kage				
	Name	Description	Version			
PDTD113EK	SC-59A	plastic surface mounted package; 3 leads	SOT346			
PDTD113ES ^[1]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
PDTD113ET	-	plastic surface mounted package; 3 leads	SOT23			

[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

4. Marking

Table 5.Marking codes

Type number	Marking code ^[1]
PDTD113EK	E1
PDTD113ES	D113ES
PDTD113ET	*7R

- [1] * = -: made in Hong Kong
 - * = p: made in Hong Kong
 - * = t: made in Malaysia
 - * = W: made in China

5. Limiting values

Table 6.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	50	V
V _{EBO}	emitter-base voltage	open collector	-	10	V
VI	input voltage				
	positive		-	+10	V
	negative		-	-10	V
lo	output current (DC)		-	500	mA
P _{tot}	total power dissipation	$T_{amb} \leq 25 ~^{\circ}C$	<u>[1]</u>		
	SOT346		-	250	mW
	SOT54		-	500	mW
	SOT23		-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7.	Thermal characteristics	5				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	<u>[1]</u>			
	SOT346		-	-	500	K/W
	SOT54		-	-	250	K/W
	SOT23		-	-	500	K/W

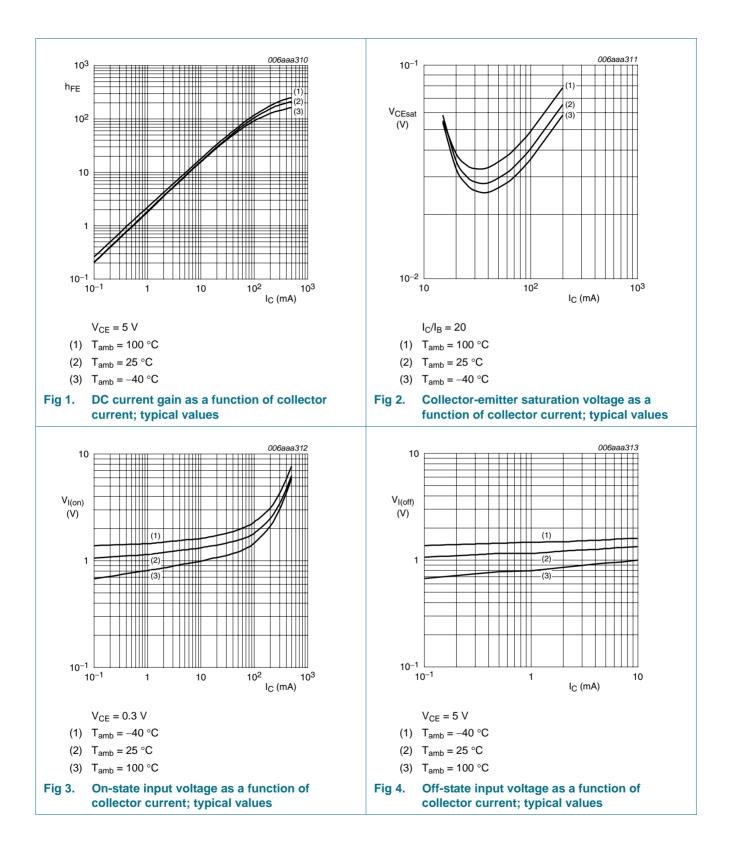
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

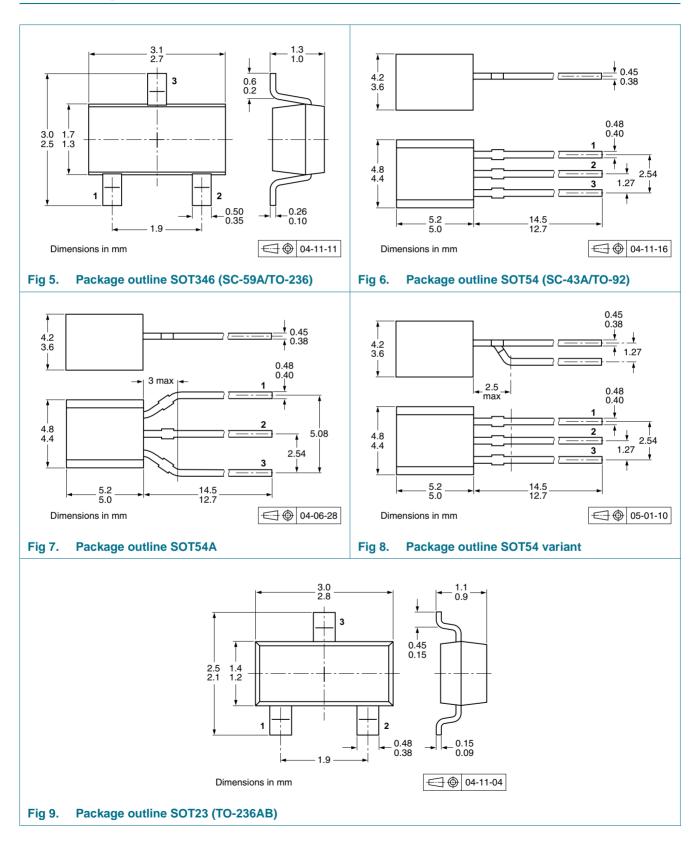
Table 8. **Characteristics** $T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified. Symbol Parameter Conditions Unit Min Тур Max collector-base cut-off $V_{CB} = 40 \text{ V}; I_F = 0 \text{ A}$ 100 -_ nA I_{CBO} current $V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$ 100 nA -collector-emitter $V_{CE} = 50 \text{ V}; I_B = 0 \text{ A}$ 0.5 μΑ **I**CEO -cut-off current $V_{EB} = 5 V; I_{C} = 0 A$ emitter-base cut-off 4 mΑ I_{EBO} -current DC current gain $V_{CE} = 5 \text{ V}; I_{C} = 50 \text{ mA}$ 33 h_{FE} -- $I_{\rm C} = 50 \text{ mA}; I_{\rm B} = 2.5 \text{ mA}$ collector-emitter 0.3 V V_{CEsat} _ saturation voltage off-state input voltage V_{CF} = 5 V; I_C = 100 μ A V 0.6 1.5 V_{I(off)} 1.1 on-state input voltage V_{CE} = 0.3 V; I_C = 20 mA 1.4 1.8 V V_{I(on)} 1.0 R1 bias resistor 1 (input) 0.7 1 1.3 kΩ R2/R1 bias resistor ratio 0.9 1 1.1 C_{c} collector capacitance $V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ 7 pF -f = 100 MHz

PDTD113E series

NPN 500 mA resistor-equipped transistors; R1 = 1 k Ω , R2 = 1 k Ω



8. Package outline



9. Packing information

Type number	Package	Description	Packin	Packing quantity		
			3000	5000	10000	
PDTD113EK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTD113ES	SOT54	bulk, straight leads	-	-412	-	
	SOT54A	tape and reel, wide pitch	-	-	-116	
		tape ammopack, wide pitch	-	-	-126	
	SOT54 variant	bulk, delta pinning	-	-112	-	
PDTD113ET	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	

[1] For further information and the availability of packing methods, see <u>Section 12</u>.

10. Revision history

Table 10. Revision h	istory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTD113E_SER_2	20091116	Product data sheet	-	PDTD113E_SER_1
Modifications:		eet was changed to reflect w legal definitions and disc		
PDTD113E_SER_1	20050414	Product data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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